

Features :

- Low forward voltage drop
- High reverse voltage
- Hermetic metal cases with ceramic insulators

$I_{F(AV)}$ 2500A
 V_{RRM} 3200 ~ 4200V
 I_{FSM} 22 kA
 I^2t 2420 $10^3 A^2s$

Typical Applications

- All purpose high power rectifier diodes
- High power resistance welding equipment
- Non-controllable and half-controllable rectifiers
- Controlled rectifiers

SYMBOL	CHARACTERISTIC	TEST CONDITIONS		$T_j(°C)$	VALUE			UNIT
					Min	Type	Max	
$I_{F(AV)}$	Mean forward current	180° half sine wave 50Hz Double side cooled,	$T_c=85°C$	160			2500	A
V_{RRM}	Repetitive peak reverse voltage	tp=10ms		160	3200		4200	V
I_{RRM}	Repetitive peak current	at V_{RRM}		160			120	mA
I_{FSM}	Surge forward current	10ms half sine wave		160			22	kA
I^2t	I^2t for fusing coordination	$V_R=0.6V_{RRM}$					2420	$A^2s \cdot 10^3$
V_{FO}	Threshold voltage			160			0.90	V
r_F	Forward slope resistance						0.125	mΩ
V_{FM}	Peak forward voltage	$I_{FM}=4000A, F=35kN$		25			1.60	V
Q_{rr}	Recovery charge	$I_{FM}=2000A, tp=4000\mu s, di/dt=-20A/\mu s, V_R=100V$		160		4600		μC
$R_{th(j-c)}$	Thermal resistance Junction to case	D.C. Double side cooled Clamping force 28kN					0.016	°C/W
$R_{th(c-h)}$	Thermal resistance case to heat sink					0.004		
F_m	Mounting force				21		30	kN
T_{vj}	Junction temperature				-40		160	°C
T_{stg}	Stored temperature				-40		160	°C
W_t	Weight					640		g
Outline	P43							

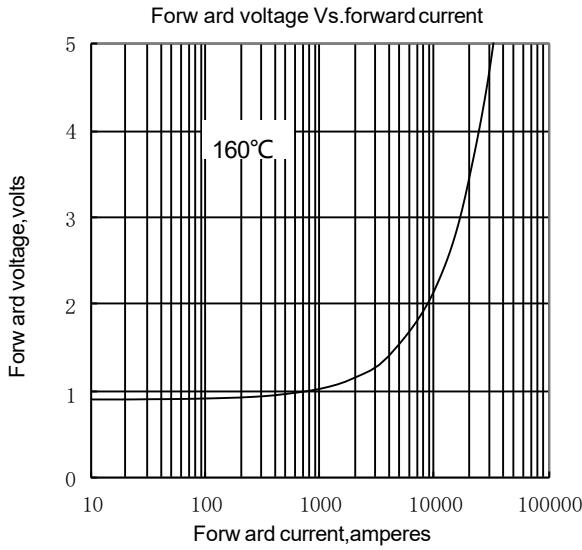


Fig.1

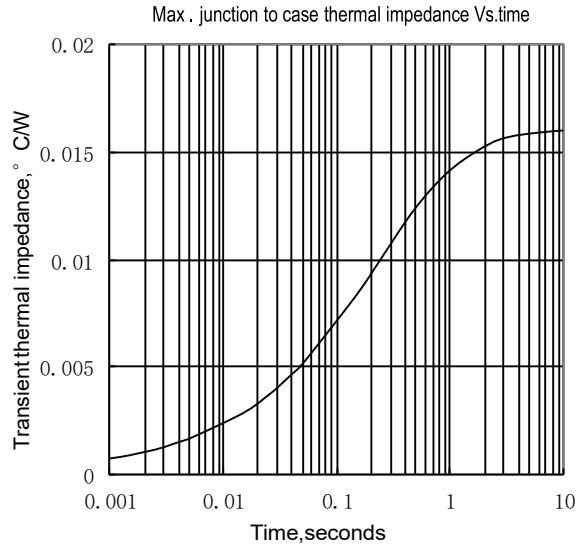


Fig.2

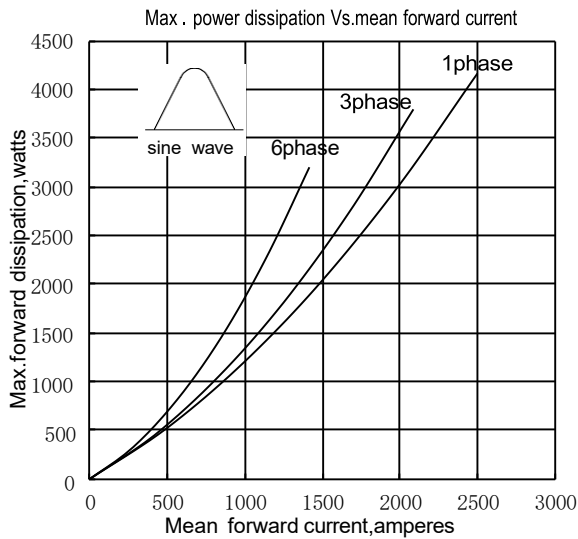


Fig.3

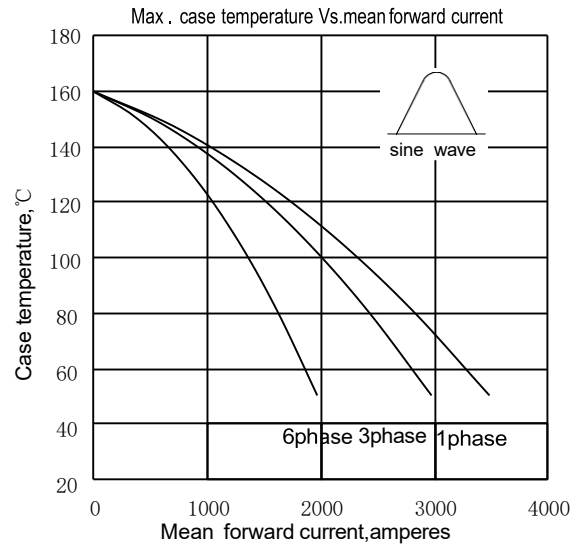


Fig.4

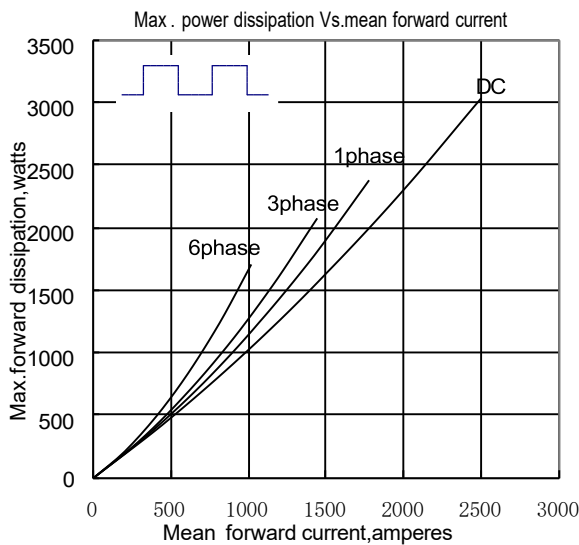


Fig.5

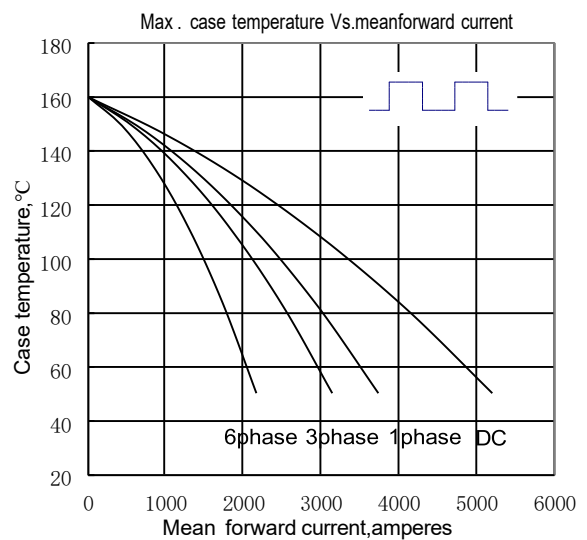


Fig.6

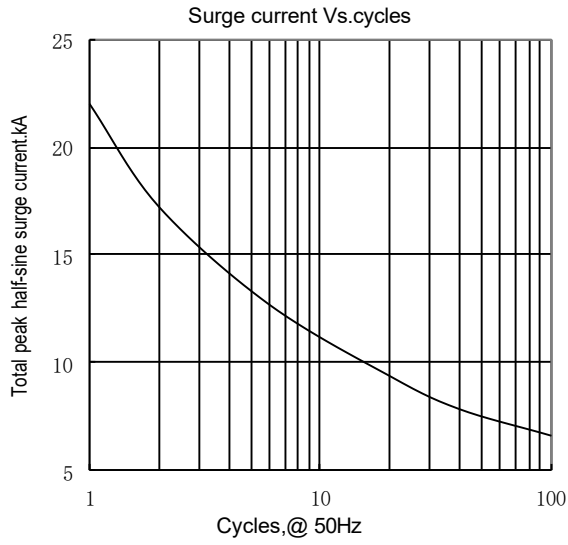


Fig.7

Outline:

